Preferred Device

# Triacs

# **Silicon Bidirectional Thyristors**

Designed primarily for full-wave ac control applications, such as motor controls, heating controls or dimmers; or wherever full-wave, silicon gate–controlled devices are needed.

- High Commutating di/dt and High Immunity to dv/dt @ 125°C
- Uniform Gate Trigger Currents in Three Quadrants, Q1, Q2, and Q3
- Blocking Voltage to 800 Volts
- On-State Current Rating of 16 Amperes RMS at 80°C
- High Surge Current Capability 150 Amperes
- Industry Standard TO-220AB Package for Ease of Design
- Glass Passivated Junctions for Reliability and Uniformity
- Device Marking: Logo, Device Type, e.g., MAC16HCD, Date Code

#### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage <sup>(1)</sup> (T <sub>J</sub> = -40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open) MAC16HCD MAC16HCM MAC16HCN	Vdrm, Vrrm	400 600 800	Volts
On–State RMS Current (Full Cycle Sine Wave 50 to 60 Hz; T <sub>C</sub> = 80°C)	IT(RMS)	16	A
Peak Non-Repetitive Surge Current (One Full Cycle, 60 Hz, T <sub>J</sub> = 125°C)	ITSM	150	A
Circuit Fusing Consideration <sup>(2)</sup> (t = 8.33 ms)	l <sup>2</sup> t	93	A <sup>2</sup> sec
Peak Gate Power (Pulse Width $\leq$ 1.0 $\mu$ s, T <sub>C</sub> = 80°C)	PGM	20	Watts
Average Gate Power (t = 8.3 ms, T <sub>C</sub> = 80°C)	PG(AV)	0.5	Watts
Operating Junction Temperature Range	Тј	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C

(1) V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

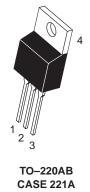


### **ON Semiconductor**

http://onsemi.com

## TRIACS 16 AMPERES RMS 400 thru 800 VOLTS





STYLE 4

	PIN ASSIGNMENT
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

#### ORDERING INFORMATION

Device	Package	Shipping
MAC16HCD	TO220AB	50 Units/Rail
MAC16HCM	TO220AB	50 Units/Rail
MAC16HCN	TO220AB	50 Units/Rail

**Preferred** devices are recommended choices for future use and best overall value.

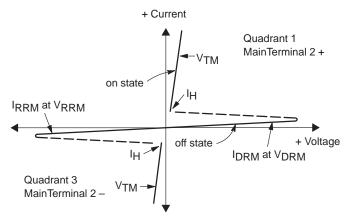
#### THERMAL CHARACTERISTICS

	Syn	nbol	Value	Unit
Thermal Resistance — Junction to Case — Junction to Ambient			2.2 62.5	°C/W
Seconds	Т	Ľ	260	°C
; Electricals apply i	n both direc	tions)		
Symbol	Min	Тур	Max	Unit
IDRM <sup>,</sup> IRRM			0.01 2.0	mA
Vтм	—	_	1.6	Volts
I <sub>GT</sub>	10 10 10	16 18 22	50 50 50	mA
Ч		20	50	mA
ιL		33 36 33	60 80 60	mA
V <sub>GT</sub>	0.5 0.5 0.5	0.80 0.73 0.82	1.5 1.5 1.5	Volts
(di/dt)c	15		_	A/ms
dv/dt	750		_	V/µs
di/dt	-	-	10	A/μs
	Symbol IDRM, IRRM VTM IGT IH IL VGT (di/dt)c dv/dt	Reg   Seconds T   Seconds T   Symbol Min   IDRM, —   IGT 10   10 10   10 10   10 10   IH —   VGT 0.5   0.5 0.5	Symbol   Min   Typ     IDRM;   —   —     IDRM;   —   —     IRRM   —   —     VTM   —   —     IGT   10   16     10   18   10   22     IH   —   20   1     IL   —   33   36     —   33   36   33     VGT   0.5   0.80   0.73     0.5   0.82   0.5   0.82     (di/dt)c   15   —   —     dv/dt   750   —   —	R $_{\theta,JC}$ 2.2 62.5       Seconds     TL     260       Symbol     Min     Typ     Max       IDRM, IRRM     —     —     —     0.01 2.0       VTM     —     —     0.01 2.0       VTM     —     —     1.6       IGT     10 10     16 50 10     50 22     50       IH     —     20     50       IL     33 60     60 80 33     80 30       VGT     0.5 0.5     0.80 0.73 0.5     1.5 1.5       (di/dt)c     15     —     —       dv/dt     750     —     —     —

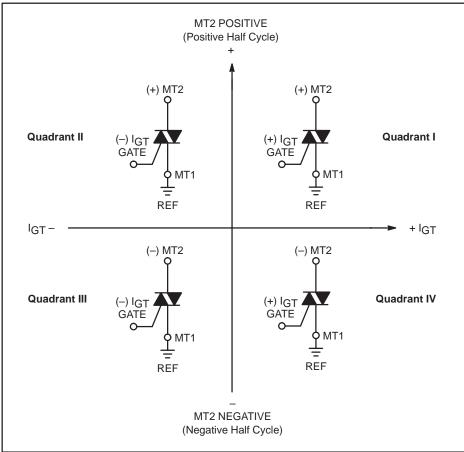
(1) Pulse Test: Pulse Width  $\leq$  2.0 ms, Duty Cycle  $\leq$  2%.

#### Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
VTM	Maximum On State Voltage
Ι <sub>Η</sub>	Holding Current

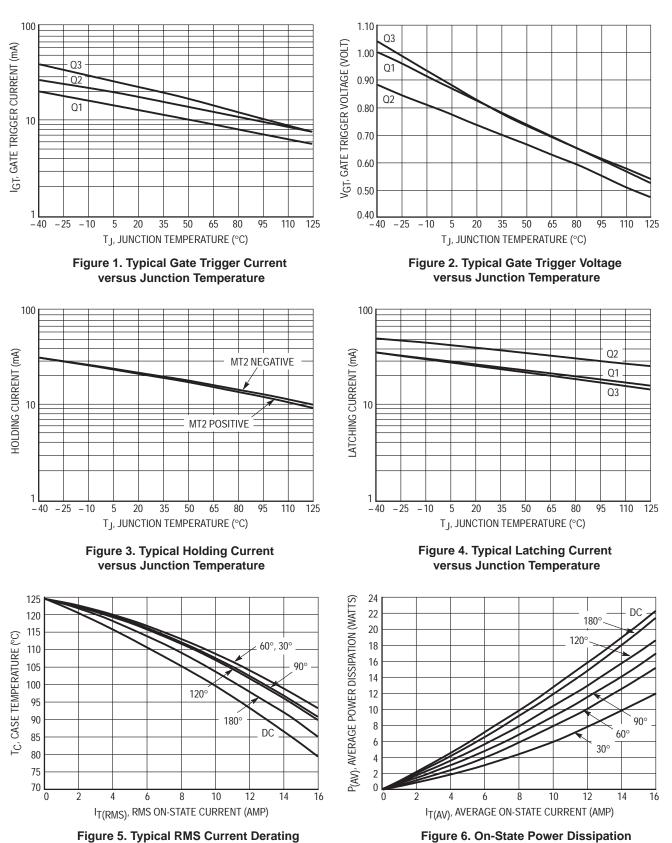


### **Quadrant Definitions for a Triac**



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.



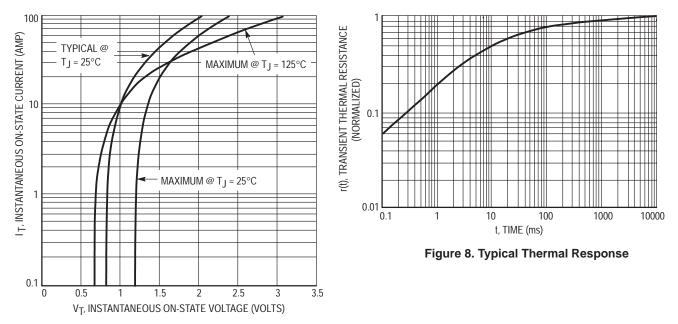
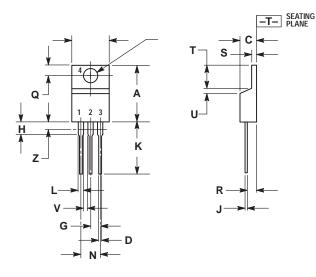


Figure 7. Typical On-State Characteristics

### PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 **ISSUE Z** 



NOTES:

IDIENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.
DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	LLIMETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.018	0.025	0.46	0.64	
К	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
Ν	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
V	0.045		1.15		
Ζ		0.080		2.04	

STYLE 4: PIN 1. MAIN TERMINAL 1 2. MAIN TERMINAL 2 3. GATE 4. MAIN TERMINAL 2

# <u>Notes</u>

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